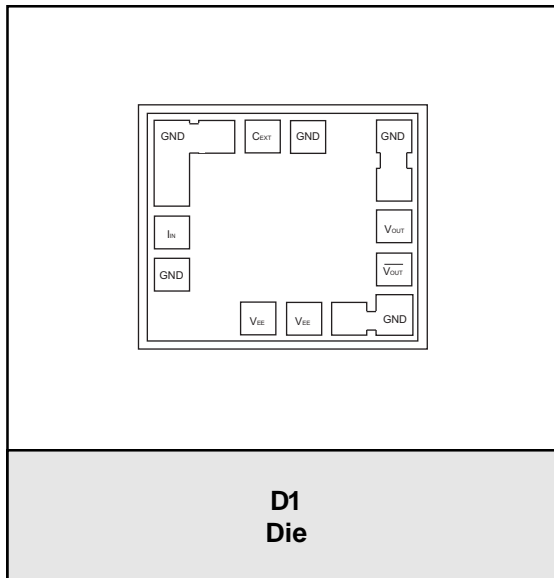


FEATURES

- 1800 Ω Differential Transimpedance
- 3 mApp Maximum Input Current
- 14 pA/ $\sqrt{\text{Hz}}$ Input Noise Current Density
- Single -5.2 V Power Supply
- Low Group Delay
- Outputs DC or AC Coupled
- Same Functionality as ATA7603 with the Output Polarities Reversed

APPLICATIONS

- SONET/SDH OC-192 /STM-64 VSR, Short-Reach, Intermediate-Reach, and Long-Reach Receivers
- 10 Gb/s Ethernet
- Fiber optic receivers, transceivers, and transponders



PRODUCT DESCRIPTION

The ANADIGICS ATA7609 is a -5.2 V high-speed transimpedance amplifier (TIA) designed for 10 Gb/s optical receiver applications available in bare die form and manufactured using an InGaP based HBT process. The device is used in conjunction with a photodetector to convert an optical signal into a differential output voltage that can be AC or DC coupled to a post amplifier. The ATA7609 has an internal overload support circuit

and can accept optical inputs as high as +3 dBm. With its low noise and high optical overload capability, the device is well suited for 10 Gb/s Ethernet and OC-192 Very Short-Reach (VSR), Short-Reach, Intermediate-Reach and Long-Reach optical receivers, transceivers and transponders. The ATA7609 is identical to the ATA7603 but with the output polarities reversed.

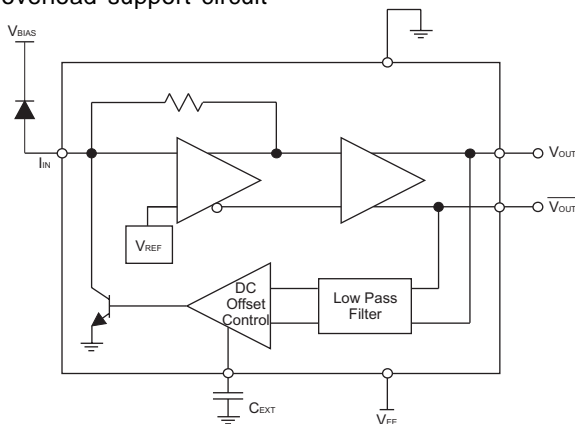


Figure 1: Circuit Block Diagram

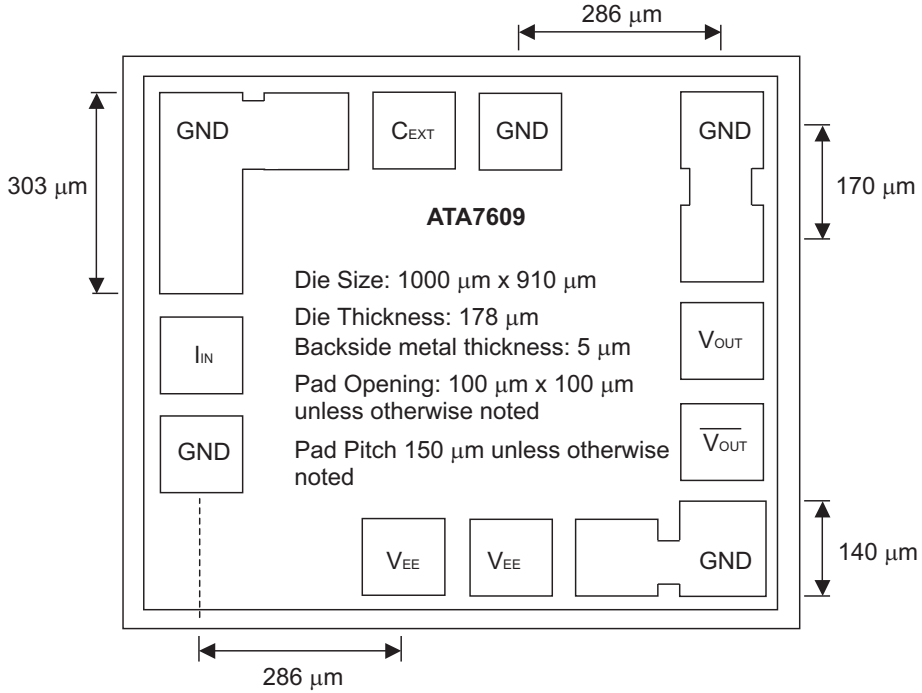


Figure 2: Die Size and Layout

Table 1: Pad Description

PAD	DESCRIPTION	COMMENTS
V _{EE}	Negative Supply Voltage	-5.2 V
GND	Ground	
I _{IN}	TIA Input	Photocurrent input
C _{EXT}	Connection for an External Capacitor	Sets the low frequency cutoff
V _{OUT}	Non-inverted Output Voltage	Logical '1' with optical input
$\overline{V_{OUT}}$	Inverted Output Voltage	Logical '0' with optical input

ELECTRICAL CHARACTERISTICS

Table 2: Absolute Minimum and Maximum Ratings

PARAMETER	MIN	MAX	UNIT
DC Power Supply (V_{EE})	-7.0	1.0	V
Storage Temperature	-65	125	°C
DC Input Current	-	5.0	mA
ESD Sensitivity (Human Body Model)	100	-	V

Stresses in excess of the absolute ratings may cause permanent damage. Functional operation is not implied under these conditions. Exposure to absolute ratings for extended periods of time may adversely affect reliability.

Table 3: Recommended Operating Conditions

PARAMETER	MIN	TYP	MAX	UNIT
Operating Voltage Range	-5.50	-5.2	-4.90	V
Operating Temperature Range ⁽¹⁾	-40	-	85	°C
Die Attach Temperature	-	-	260	°C
Photodiode Capacitance (PIN + stray)	-	0.225	0.3	pF
Photodiode Responsivity	-	0.92	-	A/W
Photodiode Contact Resistance	-	10	15	Ω
Input Bondwire Inductance	0.7	1.0	-	nH

The device may be operated safely over these conditions; however, parametric performance is guaranteed only over the conditions defined in the electrical specifications.

Notes:

(1) Defined at the interface between the die and the substrate.

Table 4: DC Electrical Specifications

PARAMETER	MIN	TYP	MAX	UNIT
Supply Current (DC Coupled Outputs)	-	95	120	mA
Input Offset Voltage	-	-3.7	-	V
Output Offset Voltage (both ports)	-	-0.2	-	V

Table 5: AC Electrical Specifications ⁽¹⁾

($V_{EE} = -5.5 \text{ V to } -4.9 \text{ V}$, Operating Temperature = $-40 \text{ }^\circ\text{C to } +85 \text{ }^\circ\text{C}$ unless otherwise noted)

PARAMETER	MIN	TYP	MAX	UNIT
Small Signal Differential Transimpedance ($R_L = 100 \ \Omega$)	1300	1800	-	Ω
Small Signal Differential Transimpedance ($R_L = 100 \ \Omega$) ⁽²⁾	1400	-	-	Ω
Small Signal Bandwidth	8.5	9.5	-	GHz
Low Frequency Cutoff ⁽³⁾	-	30	-	kHz
Peaking	-	-	1.5	dB
Group Delay Deviation (500 MHz to 8.0 GHz) ⁽⁴⁾	-	30	-	ps
Group Delay Deviation (8 GHz to 9.5 GHz) ⁽⁴⁾	-	40	-	ps
Maximum Input Current	-	-	3.0	mApp
Optical Overload ⁽⁵⁾	-	+3	-	dBm
Input Referred RMS Noise Current ⁽⁶⁾	-	1.4	-	μA
Average Input Referred Noise Current Density ⁽⁶⁾	-	14	20	$\text{pA}/\sqrt{\text{Hz}}$
Optical Sensitivity ⁽⁵⁾	-	-19	-	dBm
Maximum Single-ended Output Voltage Swing	-	400	550	mVpp
Output Return Loss (10 MHz to 8 GHz)	-	-	-10	dB
Output Return Loss (8 MHz to 20 GHz)	-	-	-5	dB

Notes:

- (1) The specifications are based upon the use of a PIN photodiode with a responsivity of 0.92 A/W and a capacitance of $C_{\text{DIODE}} + C_{\text{STRAY}} = 0.3 \text{ pF}$ max connected to I_{IN} via a 1.0 nH bond wire.
- (2) Operating temperature range = $-5 \text{ }^\circ\text{C to } +85 \text{ }^\circ\text{C}$.
- (3) With the use of an external 10 nF capacitor.
- (4) Maximum value - minimum value
- (5) Measured at 10^{-10} BER with a $2^{23} - 1$ PRBS at 10 Gb/s
- (6) Bandwidth = 9 GHz

PERFORMANCE DATA

Figure 3: Typical Small Signal Frequency Response

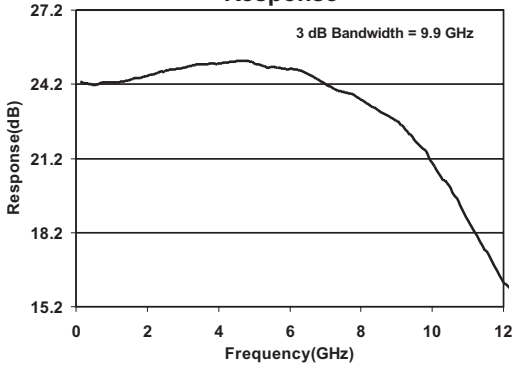


Figure 4: Typical Small Signal Group Delay

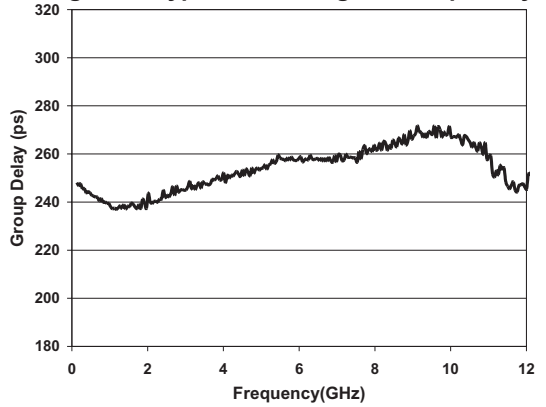


Figure 5: Bandwidth vs. Input Inductance

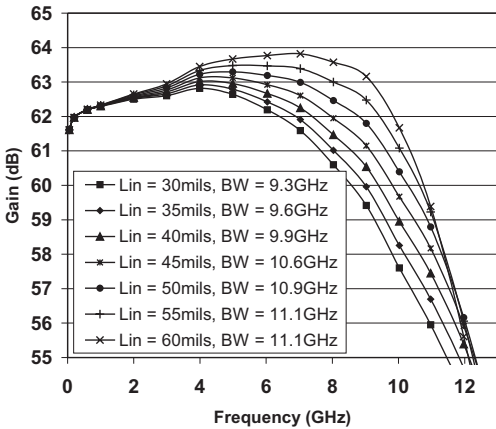


Figure 6: Differential Transimpedance vs. Input Current

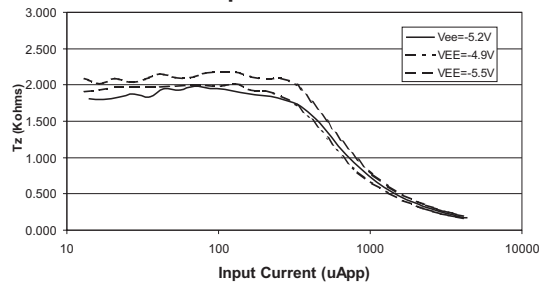


Figure 7: Differential Output Voltage vs. Input Current up to 1000 uApp

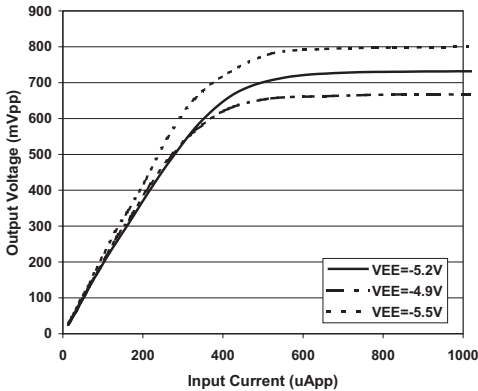


Figure 8: Differential Output Voltage vs. Input Current up to 4000 uApp

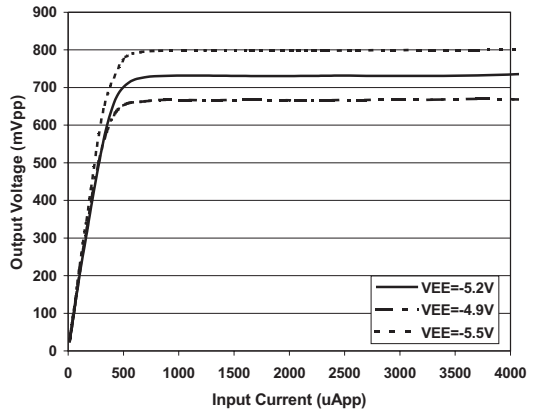


Figure 9: Eye Diagram with an Optical Input Power of -18 dBm

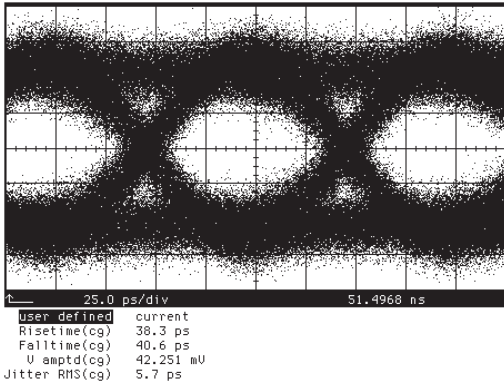


Figure 10: Eye Diagram with an Optical Input Power of -10 dBm

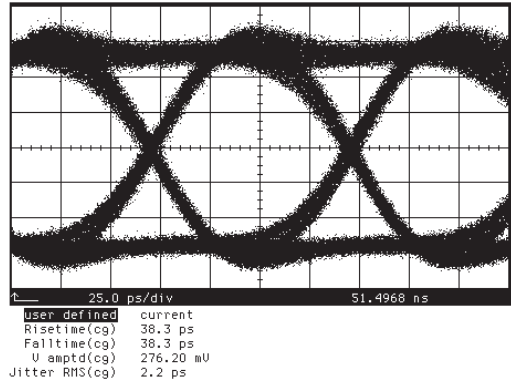


Figure 11: Eye Diagram with an Optical Input Power of 0 dBm

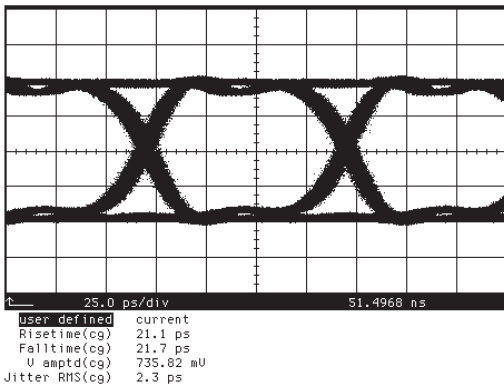


Figure 12: Eye Diagram with an Optical Input Power of +3 dBm

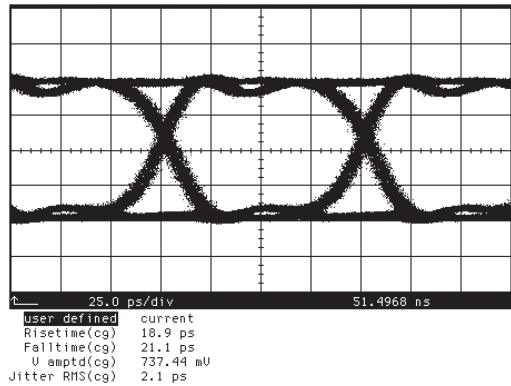


Figure 13: Eye Diagram with an Optical Input Power of +4 dBm

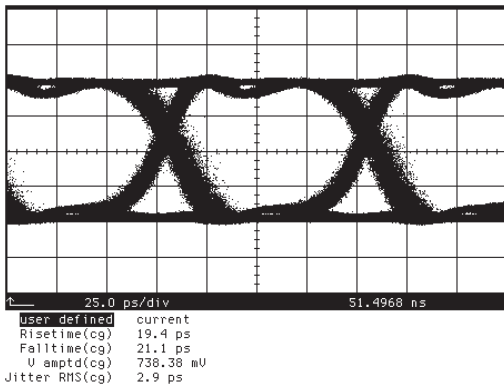
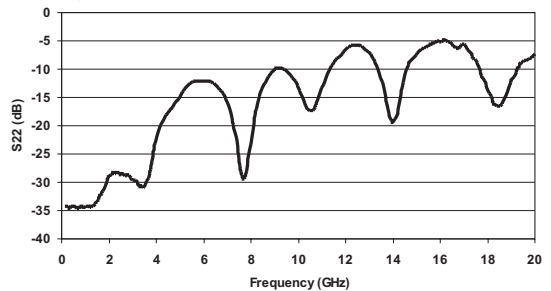


Figure 14: S22 from Evaluation Test Fixture



APPLICATION INFORMATION

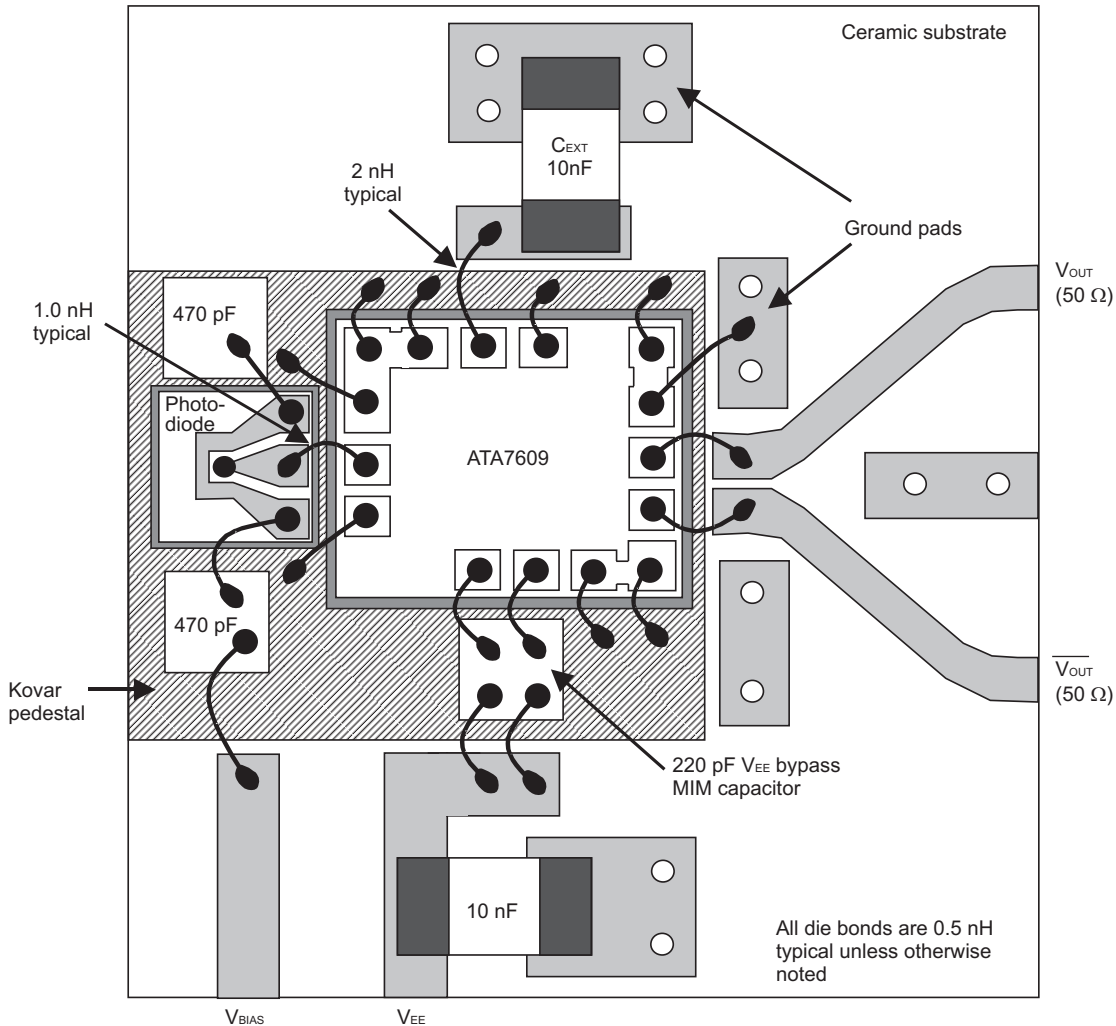


Figure 15: Bonding Diagram

PACKAGING AND TESTING

The ATA7609 is provided as bare die. For optimum performance, the die should be packaged in a hermetic enclosure and a low inductance ground plane should be made available for power supply bypassing and ground bonds. When packaging the ATA7609, the temperature of the die must be kept below 260 °C to ensure device reliability. The ATA7609 has backside metal but no ground vias are connected to the backside of the die, so it is critical to bond all of the ground pads to reduce ground inductance. The die can be attached to the substrate using epoxy or solder. A good thermally conductive, silver-filled epoxy is recommended for epoxy mounting. If solder is used for die attach, exposure to temperatures at or above 260 °C must be limited to ensure the device reliability. A soft silicon/rubber tip collet should be used for die mounting, although tweezers can be used with extreme care.

Thermosonic ball bonding, at a stage temperature of 150 to 175 °C, with 1 to 1.3 mil gold wire, is the recommended interconnect technique. The bond force, time, and ultrasonic power are all critical parameters and should be optimized to achieve the best bonding performance. The recommended bonding parameters are:

Stage Temperature: 175 °C
 Bond Time: 15 ms
 Bond Ultrasonic Power: 70 mW
 Bond Force: 70 g
 Bond Velocity: 60 mils/ms

I_{IN} Connection

For optimal performance, the bond wire from the photodetector to I_{IN} should be around 1nH. As the inductance of this connection increases beyond 1nH, more gain peaking will occur and the group delay performance will degrade.

V_{EE} Connections

In order to achieve optimal performance, the V_{EE} supply pads must be bypassed as close to the chip as possible with one or two high resonant frequency, low value capacitance, MIM capacitors. In either case, both V_{EE} bond pads need to be connected to reduce the supply bond wire inductance.

V_{OUT} and $\overline{V_{OUT}}$ Connections

The ATA7609 provides a differential output that can be AC or DC coupled to the next stage of the receiver. The output bond wires should be kept below 1 nH for the best performance. If the device is being used in a single-ended configuration, the unused output port must be terminated into 50 Ω.

C_{EXT} Connection

In order to achieve the desired low frequency cutoff, an external capacitor is required. A low inductance multilayer chip capacitor of value 10 nF is recommended.

RF Testing

The following parameters are 100% RF tested on wafer in production at -5.2V at room temperature with 0 input forced current and 1.6mA DC input current: current, transimpedance, bandwidth, peaking, group delay, S11, S22, input offset voltage and output offset voltage.

All other parameters are guaranteed by design.

TYPICAL APPLICATION CIRCUITS

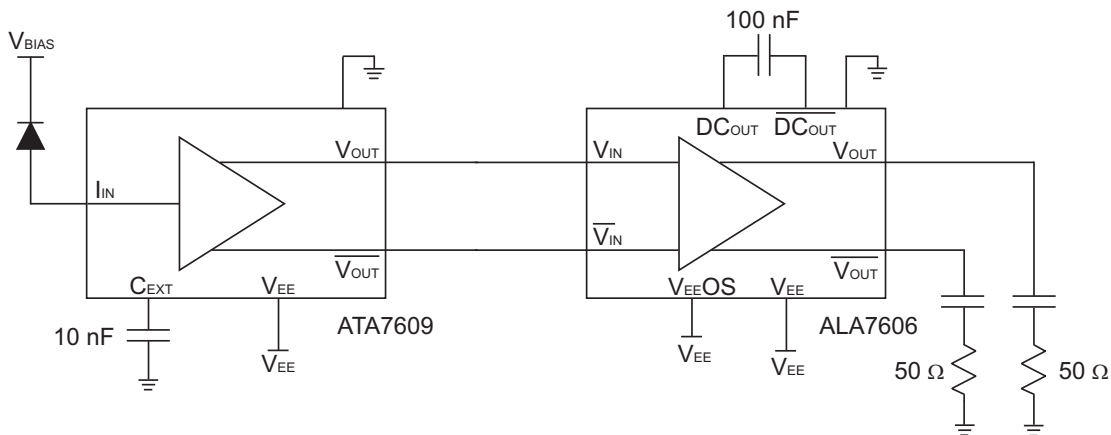


Figure 16: ATA7609 DC Coupled to the ALA7606

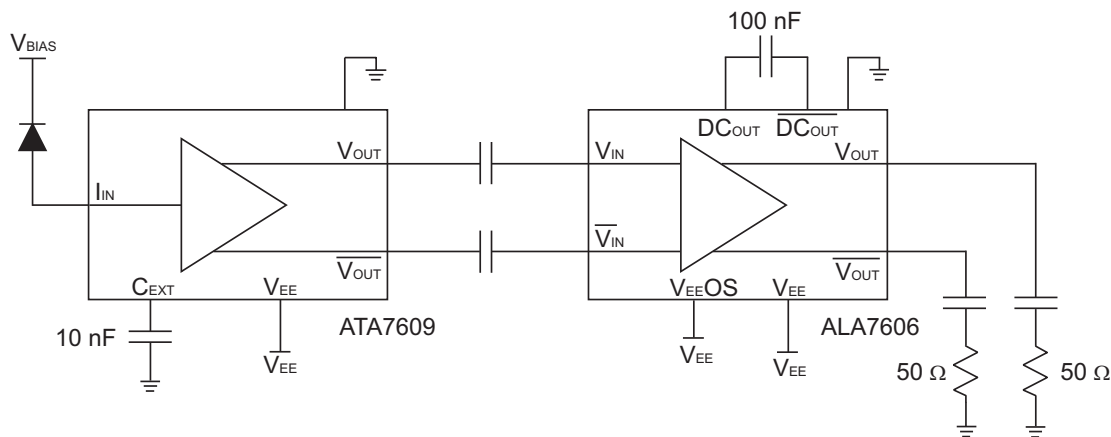


Figure 17: ATA7609 AC Coupled to the ALA7606

ATA7609

NOTES

NOTES

ORDERING INFORMATION

ORDER NUMBER	TEMPERATURE RANGE	PACKAGE DESCRIPTION	COMPONENT PACKAGING
ATA7609D1	-40 °C to +85 °C	D1	Die

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